

Cordless Telephone Signal Processor

Description

The programmable cordless phone signal processor includes all necessary low-frequency parts such as microphone- and earphone amplifier, compander, pre-emphasis, deemphasis, scrambler, FSK modem, power-supply management, as well as RF receiving parts

such as IF converter, FM demodulator, RSSI.

Several gains and mutes in transmit and receive direction are controlled by a serial bus while compander, pre- and deemphasis and scrambler can be bypassed.

Features

RF Receiver Part

- IF converter
- FM demodulator
- RSSI

Low-Frequency Part

- Symmetrical input of microphone amplifier
- Symmetrical output of earpiece amplifier

- Compander
- Pre- and deemphasis
- Scrambler
- Data management by FSK coding
- Power-supply management
- Serial bus

Applications: CT1, CT1 plus, 900 MHz USA

Block Diagram

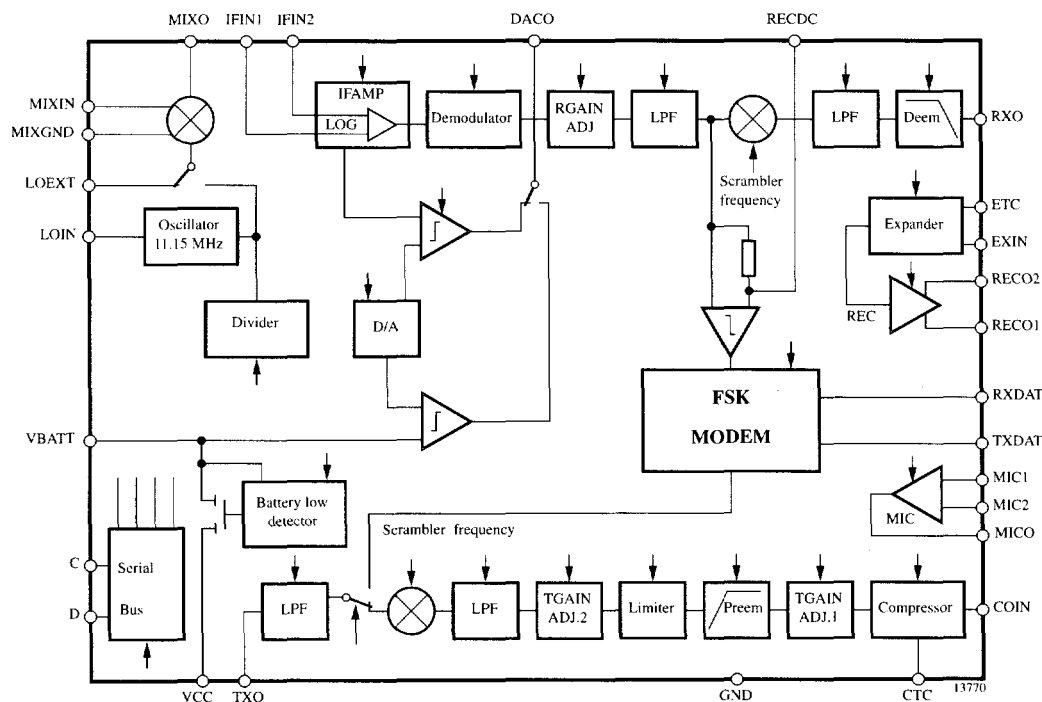


Figure 1. Block diagram

Ordering Information

Extended Type Number	Package	Remarks
U3501BM-AFL	SO28	Tube
U3501BM-AFLG3	SO28	Taped and reeled

Pin Description

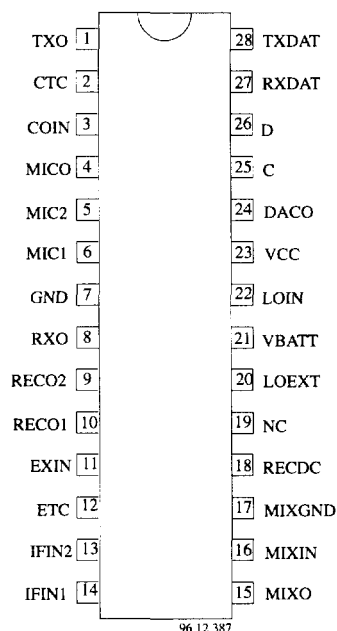
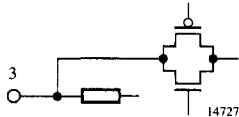
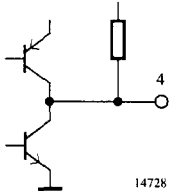
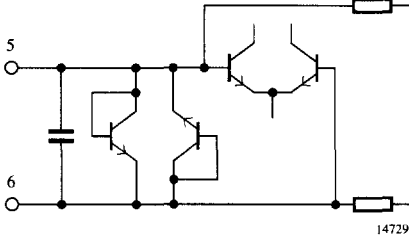
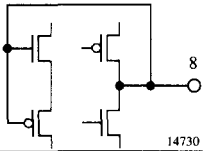
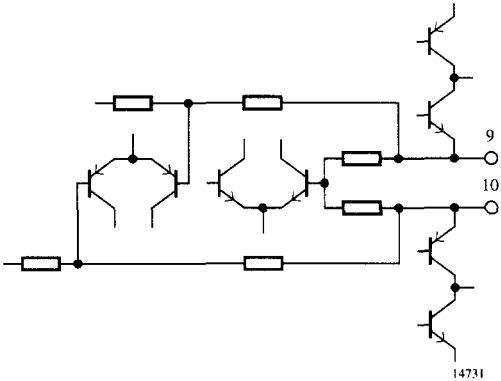
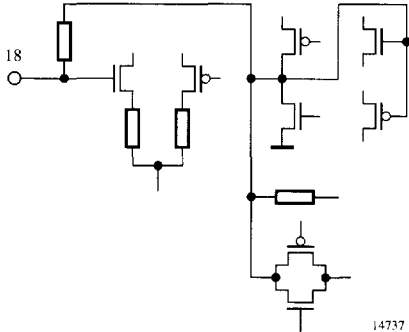
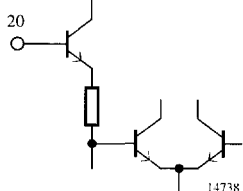
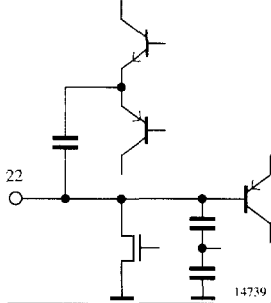
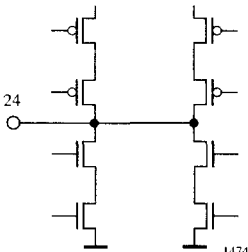


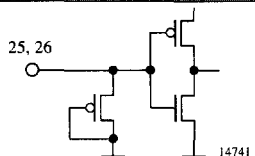
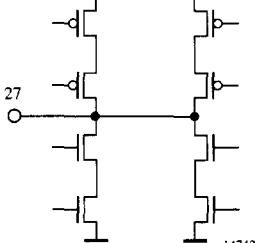
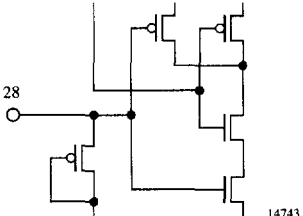
Figure 2. Pinning

Pin	Symbol	Function	Configuration
1	TXO	Transmit section analog output	14725
2	CTC	Compressor time constant control analog output	14726

Pin	Symbol	Function	Connection
3	COIN	Compressor analog input	
4	MICO	Microphone amplifier output	
5	MIC2	Non-inverting input of microphone amplifier	
6	MIC1	Inverting input of microphone amplifier	
7	GND	LF analog/ digital ground	
8	R XO	Intermediate receive analog output	
9	RECO2	Symmetrical output of receive amplifier	
10	RECO1	Symmetrical output of receive amplifier	

Pin	Symbol	Function	Configuration
11	EXIN	Expander analog input	
12	ETC	Expander time constant control analog output	
13	IFIN2	Symmetrical IF amplifier input	
14	IFIN1	Symmetrical IF amplifier input	
15	MIXO	Mixer output	
16	MIXIN	Mixer input	
17	MIXGND	IF amplifier and mixer ground	

Pin	Symbol	Function	Configuration
18	REDCD	Reference-voltage generation for FSK demodulator	
19	NC	Not connected	
20	LOEXT	External LO input	
21	VBATT	Battery supply	
22	LOIN	Local oscillator input for TCO or SC filter oscillator: 11.15 MHz	
23	VCC	Supply-voltage output for peripherals and internal supply of digital part	
24	DACO	D/A comparator output	

25	C	Clock input of serial bus	
26	D	Data input of serial bus	
27	RXDAT	Receive data digital output	
28	TXDAT	Transmit data digital input	

Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Supply voltage	V_{Batt}, V_{CC}	5.5	V
Junction temperature	T_j	+125	°C
Ambient temperature	T_{amb}	-25 to +75	°C
Storage temperature	T_{stg}	-50 to +125	°C
Power dissipation $T_{amb} = 60^{\circ}\text{C}$	P_{tot}	1	W

Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient SO28	R_{thJA}	120	K/W

Electrical Characteristics

Test conditions (unless otherwise specified): $V_{Batt} = V_{CC} = 3.6\text{ V}$, $T_{amb} = +25^{\circ}\text{C}$

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit	Fig.	
Current consumption								
ERX2	ELNA	ERXHF	ERX1	ERXO	EEA	EDEE	ETX	EPREE
0	0	0	0	0	0	0	0	0
Operating-voltage range				3.1	3.6	4.7	V	
Inactive mode		V _{Batt} = 2.9 V		30	60	80	μA	
Standby mode					0.3	0.5	mA	
RX waiting for RSSI		ERXHF = 1		1.0	1.6	2.4	mA	
RX demodulating MODEM-signal		ERXHF = ERX1 = 1		1.7	2.6	3.7	mA	
Operating current, RX and TX completely active		ERX2 = ELNA = ERXHF = ERX1 = ERXO = EEA = EDEE = GDEM = ETX = 1			7	11.5	mA	
Input resistance				2	3	4	kΩ	3
Input capacitance					3		pF	3
Output impedance				1.2	1.5	1.8	kΩ	3
Gain GVMIX		Input level 7 mV _{rms}	G _{MIX}	13	15	17	dB	3
Input compression point				-17			dBm	3
Third-order input intercept point				-9			dBm	3
Carrier breakthrough from internal LO (11.15 MHz) to IF output						300	μV _{rms}	3
Carrier breakthrough from internal LO (11.15 MHz) to RF input						10	μV	3
Receiver								
IF mixer, f = 10.7 MHz								
IF amplifier: RSSI								
Input resistance				1.6	2	2.5	kΩ	4
RSSI sensitivity		V _{IF} = 0 μV _{rms} starting from 0 increase RSSI level until mean of sampled signal at DAC0 is ≤ 0.2 RSSI level = CON0 V _{IF} = 6 μV _{rms} , F = 450 kHz increase RSSI level again until mean of sampled signal at DAC0 is ≤ 0.2. RSSI level = CON1 RSSI sensitivity = CON1-CON0		4				4
RSSI input voltage dynamic range					65		dB	4
RSSI level number of steps *)					127			4
RSSI level step-size in the logarithmic region					0.46		dB	4

*) RSSI Level programming (typical values) see next page

***) RSSI Level Programming (Typical Values)**

Input Voltage V_{IF} (μV_{rms})	RSSI Level (Decimal)
0	8
6	15
10	23
100	67
1000	114
10000	

Parameters	Test Conditions			Symbol	Min.	Typ.	Max.	Unit	Fig.
RF demodulator $f_{IF} = 450 \text{ kHz}$, $f_{mod} = 1 \text{ kHz}$, $V_{IF} = 500 \mu V_{rms}$									
BSCR	EDEE	GRX0	GRX1	GRX2	GRX3	ERX1	ERX0		
1	0	1	1	1	0	1	1		
Recovered audio (peak-to-peak)		GDEM = 0, $\Delta f_{FM} = 2.5 \text{ kHz}$ GDEM = 1, $\Delta f_{FM} = 5 \text{ kHz}$			0.4 0.4	0.8 0.8	1.6 1.6	V V	5
Recovered audio output voltage drop		$V_{Batt} = 3.2 \text{ V to } 4.7 \text{ V}$			-3			dB	5
AM rejection ratio		30% AM				35		dB	5
RX audio, GDEM = 0									
Change of RX0 signal deemphasis bypass		EDEE = 0; 1			-0.5	0	0.5	dB	5
Gain-adjust range						15		dB	5
Gain-adjust step					0.8	1	1.2	dB	5
Output signal vs. frequency relative to 1 kHz (0 dB) deemphasis bypassed		100 Hz			-8.0	-7.0	-6.0	dB	5
		300 Hz			-2.2	-1.2	-0.2		
		1800 Hz			-1.4	-0.4	0.6		
		3400 Hz			-0.8	0.2	1.2		
		4350 Hz			-80	-60	-55		
Output signal versus frequency relative to 1 kHz (0 dB) deemphasis enable EDEE = 1		100 Hz			-1.6	-0.6	0.4	dB	5
		300 Hz			3.2	4.2	5.2		
		1800 Hz			-5.7	-4.7	-3.7		
		3400 Hz			-10.5	-9.5	-8.5		
		4350 Hz			-80	-60	-55		
Total harmonic distortion		$\Delta FM = 250 \text{ Hz}$ $\Delta FM = 2.50 \text{ kHz}$					2.5 2.5	%	5
Audio mute		$\Delta FM = 2.5 \text{ kHz}$ ERX0 = 0 ERX1 = 0 ERX2 = 0			65			dB	5
Output impedance							100	Ω	5

Parameters		Test Conditions		Symbol	Min.	Typ.	Max.	Unit	Fig.		
Expander											
EEA 1	GEA0 0	GEA1 0	GEA2 0	GEA3 1	GEA4 1						
Gain-reference level		V _{EXIN} = −10 dBV _{rms}			GOREC	11	13	15	dB	6	
Change of gain when expander is bypassed		BCOMP = 1				−0.5		0.5	dB	6	
Gain tracking		V _{EXIN} = −20 dBV _{rms} V _{EXIN} = −30 dBV _{rms} V _{EXIN} = −35 dBV _{rms} V _{EXIN} = −40 dBV _{rms}				−21 −41 −53	−50 −60	−19 −39 −47	dB	6	
Input impedance						9.5		14.5	kΩ	6	
Gain change versus supply voltage		V _{Batt} = 3.2 V to 4.7 V				−0.5		0.5	dB	6	
Attack time		V _{EXIN} = step −20 dBV _{rms} → −14 dBV _{rms} , measure time after step when output voltage is 0.75 times the final value			t _r		16		ms	6	
Release time		V _{EXIN} = step 14 dBV _{rms} → −20 dBV _{rms} , measure time after step when output voltage is 1.5 times the final value			t _f		16		ms	6	
Earpiece amplifier BCOMP = 1, EEA = 1, V _{EXIN} = 100 mV _{rms}											
Maximum gain		GEA0 1	GEA1 1	GEA2 1	GEA3 1		19	20	21	dB	6
		GEA4 = 1									
Medium gain		GEA0 0	GEA1 0	GEA2 0	GEA3 0		4	5	6	dB	6
		GEA4 = 1									
Minimum gain		GEA0 0	GEA1 0	GEA2 0	GEA3 0		−12	−11	−10	dB	6
		GEA4 = 0									
Gain change vs. supply voltage		V _{Batt} = 3.2 V to 4.7 V				−0.2		0.2	dB	6	
Gain-adjust range							31		dB	6	
Gain-adjust step						0.8	1	1.2	dB	6	
Output impedance							10	30	Ω	6	
Distortion					d _t			1	%	6	
Output offset voltage		V _{EXIN} = 0 mV _{rms}				−200		200	mV	6	
Output-voltage swing (peak-to-peak)		Increase V _{EXIN} until distortion (RECO1/ RECO2) is 5%			V _{pp}	4.8	5.0		V	6	

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit	Fig.
Low-frequency transmitter							
GMIC	EPREE	BXCR	G1TX	G2TX	BCOMP	ETX	
1	1	1	1000	1000	1	1	
Microphone amplifier $V_{MIC} = 10 \text{ mV}_{rms}$, $f_{IN} = 1 \text{ kHz}$							
Gain	High gain: GMIC = 1 Low gain: GMIC = 0		31 23	32 24	33 25	dB	7
Gain change vs. supply voltage	$V_{Batt} = 3.2 \text{ V to } 4.7 \text{ V}$		-0.2	0	0.2	dB	7
Differential input impedance			41	75	103	k Ω	7
Output impedance				10	35	Ω	7
Distortion	$V_{MIC} = 10 \text{ mV}_{rms}$	d_t			1	%	7
Output noise (psophmetically weighted)	$V_{MIC} = 0 \text{ V}_{rms}$ high gain (inputs closed across 200 Ω)				50	μV_{rmsp}	7
TX audio $V_{COIN} = -20 \text{ dBV}_{rms}$							
Gain	GTX (TXO, COIN)		2.5	5.5	8.5	dB	8
Change of gain TXO	EPREE = 0		-0.5	0	0.5	dB	8
Gain between 3.2 and 4.7 V			-1	0	-1	dB	8
TX gain-adjust range adj. 1				15		dB	8
TX gain-adjust step adj. 1			0.8	1	1.2	dB	8
LIM gain-adjust range adj. 2				15		dB	8
LIM gain-adjust range adj.2			0.8	1	1.2	dB	8
TX gain versus frequency (pre-emphasis bypassed) relative to 1 kHz reference level 0 dB	100 Hz 300 Hz 1800 Hz 3400 Hz 4350 Hz		-1.3 -1.2 -0.8 -1.1 -20.0	-0.3 -0.2 0.2 -0.1 -24.0	0.7 0.8 1.2 0.7 -28.0	dB	8
Gain versus frequency with pre-emphasis relative to 1 kHz reference level 0 dB	100 Hz 300 Hz 1800 Hz 3400 Hz 4350 Hz		-7.5 -6.5 3.3 6.9 -15.0	-6.5 -5.8 4.3 7.0 -14.0	-5.5 -4.5 5.3 8.9 -13.0	dB	8
Total band ripple	$V_{Batt} = 3.2 \text{ V to } 4.7 \text{ V}$ $V_{COIN} = -20 \text{ dBV}$				2	dB	8
Limiter							
Output voltage (peak-to-peak)	Increase V_{COIN} until $d \approx 5\%$ at TX0 then measure V_{TX0}		1.2	1.68	2.3	V	
Mute	ETX = 0, $V_{COIN} = -10 \text{ dBV}$ attenuation at TX0 output		65			dB	
Output impedance			7	10	14	k Ω	

Parameters	Test Conditions					Symbol	Min.	Typ.	Max.	Unit	Fig.
Compander / compressor											
BSCR	EPREE	G2TX0	G2TX1	G2TX2	G2TX3	ETX	G1TX0	G2TX1	G1TX2	G1TX3	
1	0	0	1	0	1	1	0	0	1	0	
Input impedance		BCOMP = 1					9	14	22	kΩ	8
Gain reference level G0TX		V _{COIN} = -10 dBV _{rms}				G _{0TX}	1	5.5	10	dB	8
Gain change when compressor is bypassed		V _{COIN} = -10 dBV _{rms} BCOMP = 1					0.5		0.5	dB	8
Gain tracking		V _{COIN} = -30 dBV _{rms} V _{COIN} = -50 dBV _{rms} V _{COIN} = -60 dBV _{rms} V _{COIN} = -70 dBV _{rms}					-11 -21 -22		-9 -19 -28	dB	8
Attack time		V _{COIN} = step -30 dBV _{rms} → -18 dBV _{rms} measure time after step when output voltage is 1.5 times the final value				t _r		3.5		ms	8
Release time		V _{COIN} = step -18 dBV _{rms} → -30 dBV _{rms} measure time after step when output voltage is 0.75 times the final value				t _f		14.4		ms	8
Scrambler											
EPREE	BSCR	BCOMP									
0	0	1									
Conversion gain versus frequency f _{IN} (1 kHz) reference level 0 dB		f _{IN} =100Hz, f _{OUT} =4255Hz f _{IN} =300Hz, f _{OUT} =4055Hz f _{IN} =700Hz, f _{OUT} =3655Hz f _{IN} =1800Hz, f _{OUT} =2555Hz f _{IN} =2600Hz, f _{OUT} =1755Hz f _{IN} =3400Hz, f _{OUT} =955Hz f _{IN} =3600Hz, f _{OUT} =755Hz f _{IN} =1000Hz, f _{OUT} =3355Hz					-4.5 -2.3 -0.9 -1.1 -1.1 -2.5 -4.9 -1	-3.5 -1.3 0.1 -0.1 -0.1 -1.5 -3.9 0	-2.5 -0.3 1.1 0.9 0.9 -0.5 -2.8 1	dB	9
Carrier break through		Measure f _{OUT} = 4355 kHz						10	20	mV _{rms}	
Descrambler											
EDEE	BSCR	BCOMP									
0	0	1									
Conversion gain versus frequency		f _{IN} =4255Hz, f _{OUT} =100Hz f _{IN} =4055Hz, f _{OUT} =300Hz f _{IN} =3655Hz, f _{OUT} =700Hz f _{IN} =2555Hz, f _{OUT} =1800Hz f _{IN} =1755Hz, f _{OUT} =2600Hz f _{IN} =955Hz, f _{OUT} =3400Hz f _{IN} =755Hz, f _{OUT} =3600Hz f _{IN} =3355Hz, f _{OUT} =1000Hz					-3.8 -1.6 -0.5 -1.7 -0.7 -1.4 -1.7 -1	-2.6 -0.6 0.5 -0.7 6.3 -0.4 -0.7 0	-1.8 0.1 1.5 0.3 1.3 0.6 0.3 1	dB	9
Carrier break through		Measure f _{OUT} = 4355 kHz						0.1	0.5	mV _{rms}	

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit	Fig.
FSK modem (1200 Bauds)							
FSK-demodulator	IFIN = 450 kHz						
Input signal discriminator	VIFIN = 0.5 mV _{rms}						
IFIN1-IFIN2—RXDAT	df = 2.4 kHz						
	ERX1 = 1						
2100 Hz — = 0	GDEM = 0 (high gain)		1720			Hz	
1300 Hz — = 1	GRX3 = 1 (+1dB)				1660	Hz	
FSK – modulator	ETX = 1						
TXDAT — TXO	EFSK = 1						
Output signal level	TXDAT = 0		0.87		1.54	V _{pp}	
TXDAT — TXOUT	TXOUT = 2100 Hz						
	TXDAT = 1				1.54	V _{pp}	
	TXOUT = 1300 Hz						
Signal distortion	TXDAT = 0						
TXDAT — TXOUT	TXOUT = 2100 Hz				2	%	
	TXDAT = 1						
	TXOUT = 1300 Hz				2	%	
Output signal frequency	TXDAT = 0		2100			Hz	
	TXDAT = 1		1300				
Output signal				2		%	
– Distortion							
– Offset level			1.5			V	
Logical part							
Inputs: C, D, TXDAT							
Low-voltage input					0.5	V	
High-voltage input			2.5			V	
Input leakage current			–1			μA	
(0 < V _I < V _{CC})					1	μA	
Input LOIN							
Input leakage current pin			–5		5	μA	
XCK (0 < V _I < V _{CC})							
Outputs: DACO, RXDAT							
Output low	I _{ol} = 10 μA				0.1 × V _{CC}		
Output high	I _{oh} = –10 μA		0.9 × V _{CC}				
Serial bus							
Data set-up time		t _{sud}	0.1			μs	
Data hold time		t _{hd}	0			μs	
Clock low time		t _{cl}	2			μs	
Clock high time		t _{ch}	2			μs	
Hold time before transfer		t _{eon}	0.1			μs	
condition							
Data low pulse on transfer		t _{eh}	0.2			μs	
condition							
Data high pulse on transfer		t _{eof}	0.2			μs	
condition							

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit	Fig.
Battery management							
Max. battery low	DA0 to 6 = 1, RBAT = 1		3.8	3.95	4.1	V	
Min. battery low over switch	DA0 to 6 = 27 BIN, RBAT = 1		3.05	3.2	3.35	V	
Max. battery high	DA0 to 6 = 1, RBAT = 0		4.85	5.05	5.25	V	
Min. battery high	DA0 to 6 = 0, RBAT = 0		3.93	4.1	4.27	V	
Adjust step			3.5	7.5	11.5	mV	
Max. – Min.			852.5	952.5	1052.5	mV	
MINBL – SWOFF			100	200	300	mV	
Battery switch							
Off threshold	DA0 to 6 = 1, RBAT = 1		2.9	3.0	3.1	V	
On threshold	DA0 to 6 = 27 BIN, RBAT = 1		3.15	3.25	3.35	V	
Hysteresis			220	250	280	mV	
Switch R_{on}	DA0 to 6 = 0, RBAT = 0			35	50	Ω	

Max batlow : MAXBL (battery voltage when all DAC bits are high, low range)
Min batlow : MINBL (battery voltage when DAC bits are 0011011, low range)
Max bathigh : MAXBH (battery voltage when all DAC bits are high, high range)
Min bathigh : MINBH (battery voltage when all DAC bits are low, high range)
Adjust step : Adjust step
Max – Min : MAXBH – MINBH
MINBL – SWOFF : MINBL – SWOFF
Off threshold : SWOFF (off threshold of the battery switch)
On threshold : SWON (on threshold of the battery switch)
Hysteresis : SWON – SWOFF
Switch R_{on} : Switch R_{on} (resistance of the switch transistor, when switch is “ON”)

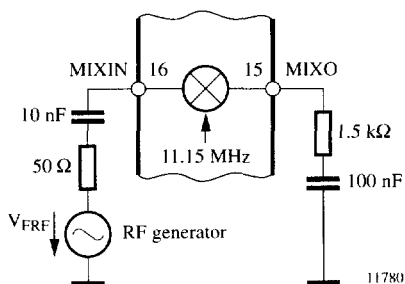


Figure 3. Test circuit

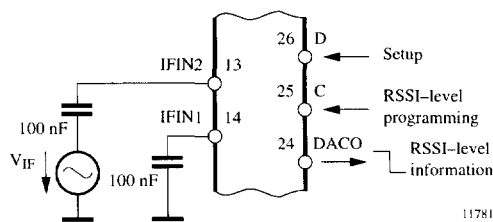


Figure 4.

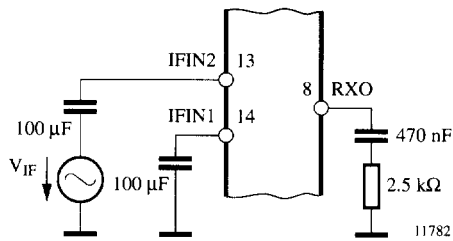


Figure 5.

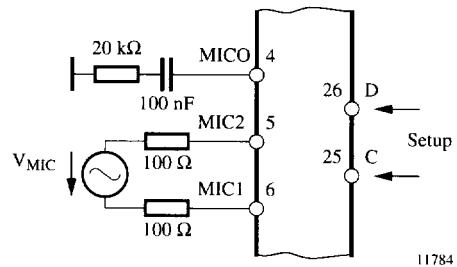


Figure 7.

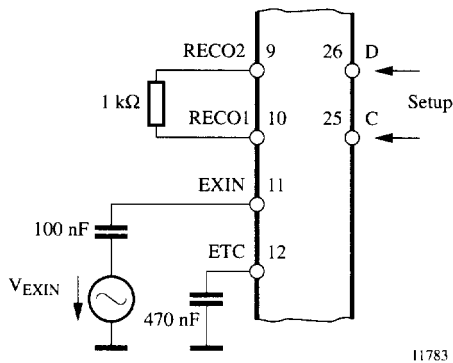


Figure 6.

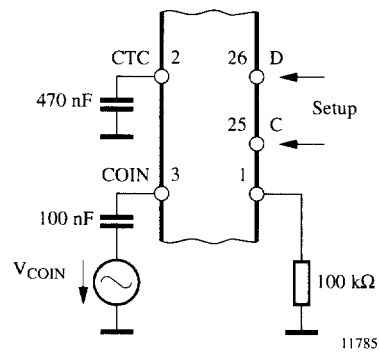
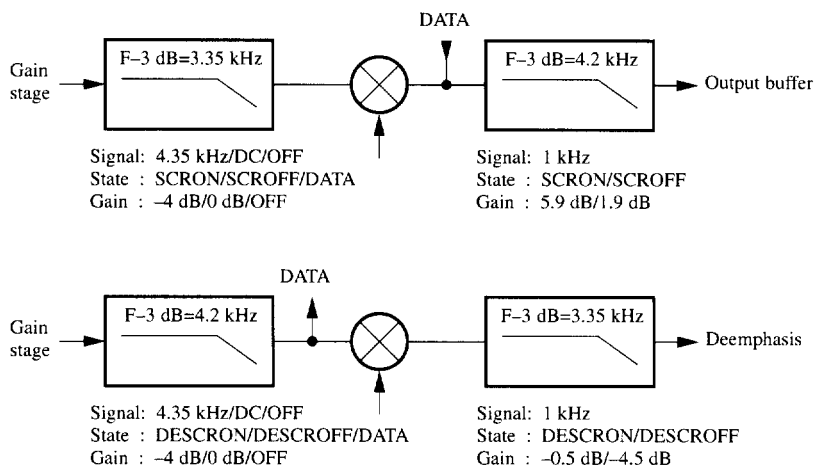


Figure 8.



13320

Figure 9.

Serial Bus Interface

The circuit is remoted by an external microcontroller trough the serial bus.

The data is a 12-bit word:

A3 – A0: address of the destination register (0 to 15)

D7 – D0: contents of register

The data line must be stable when the clock is high and data must be shifted serially.

After 12 clock periods, the transfer to the destination register is generated (internally) by a low to high transition of the data line when the clock is high.

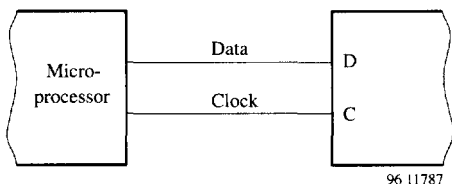


Figure 10.

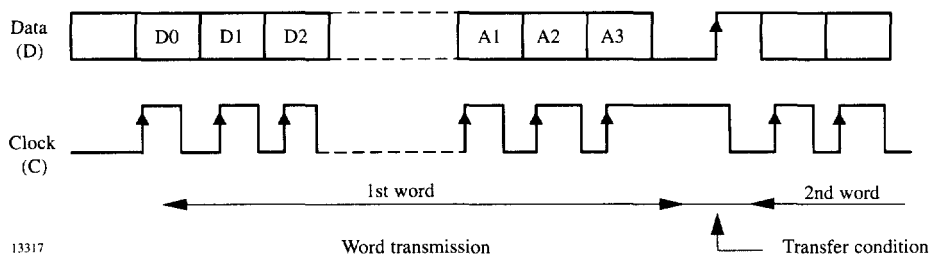


Figure 11. Serial bus transmission

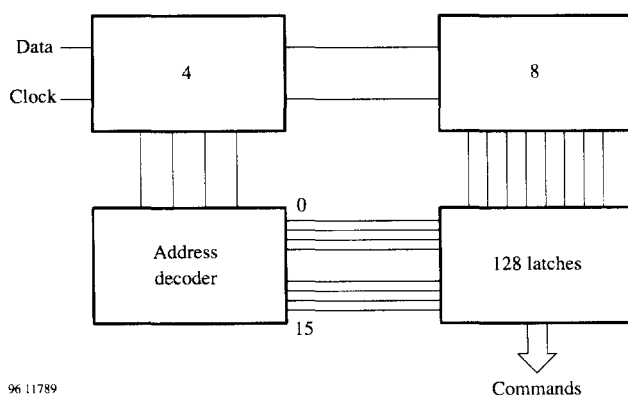


Figure 12.

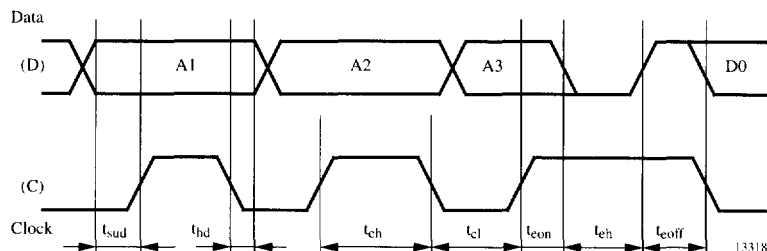


Figure 13.

Content of Internal Registers

The register have the following structure:

D7	D6	D5	D4	D3	D2	D1	D0
----	----	----	----	----	----	----	----

R0: Reference for D/A converter

MUXDA	DA6	DA5	DA4	DA3	DA2	DA1	DA0
-------	-----	-----	-----	-----	-----	-----	-----

MUXDA: D/A multiplexing

DA(6:0): Reference voltage D/A

R1: Gain adjustment RECLF

GEA3	GEA2	GEA1	GEA0	GRX3	GRX2	GRX1	GRX0
------	------	------	------	------	------	------	------

GEA(3:0): Gain earpiece amplifier (see also R5)

GRX(3:0): Gain adjustment RX

R2: Gain adjustment TRANLF

G2TX3	G2TX2	G2TX1	G2TX0	G1TX3	G1TX2	G1TX1	G1TX0
-------	-------	-------	-------	-------	-------	-------	-------

G2TX(3:0): Gain adjustment TX after limiter

G1TX(3:0): Gain adjustment TX

R3: Enable functions receive

GDEM	EDDE	EEA	ERXO	ERX1	ERXHF	free	ERX2
------	------	-----	------	------	-------	------	------

GDEM: Gain demodulator

EDDE: Enable deemphasis (disables bypass)

EEA: Enable earpiece amplifier

ERXO: Enable RXO output

ERXHF: Enable mixer and IF amplifier

ERX(1:2): Enable parts of RXLF

R4: Enable functions transmit

SRSSI	RBAT	BCOMP	BSCR	GMIC	EFSK	EPREE	ETX
-------	------	-------	------	------	------	-------	-----

SRSSI: RSSI sample hold
 RBAT: Battery detection high/low range
 BCOMP: Bypass compressor and expander
 BSCR: Bypass scrambler and descrambler
 GMIC: Gain of microphone preamplifier
 EFSK: Enable modulator of FSK modem
 EPREE: Enable pre-emphasis (disables bypass)
 ETX: Enable TX low frequency part

R5:

free	MTX	free	free	free	free	GEA4	EXTLO
------	-----	------	------	------	------	------	-------

GEA4: Gain earpiece amplifier MSB (see also R1)
 EXTLO: Select input mixer
 MTX: Mute transmit section

Example of Mode Setting Using Enable Bits and Battery Switch

U3501BM, see figure 14

	Active Mode (Transmission)	Active Mode (PLL Convergence Waiting)	Receive Mode (Only Data)	Receive Mode (RX Waiting)	Standby Mode (ex: Battery Low)	Inactive Mode (Switch Off)
Transmitter *MC	X					
*ETX, ERX2, ERXO	X	X				
ERX1	X	X	X			
ERXHF, ELNA *EVCO3 RSSI/Battery Management (MUXDA)	X	X	X	X		
MC + LOGIC PART (Enabled when $V_{Batt} > 3.2V$)	X	X	X	X	X	
Switch Comparator of VCC (Always Enabled)	X	X	X	X	X	X

MC = Microcontroller, *MC = Link directly from microcontroller

Application Circuit

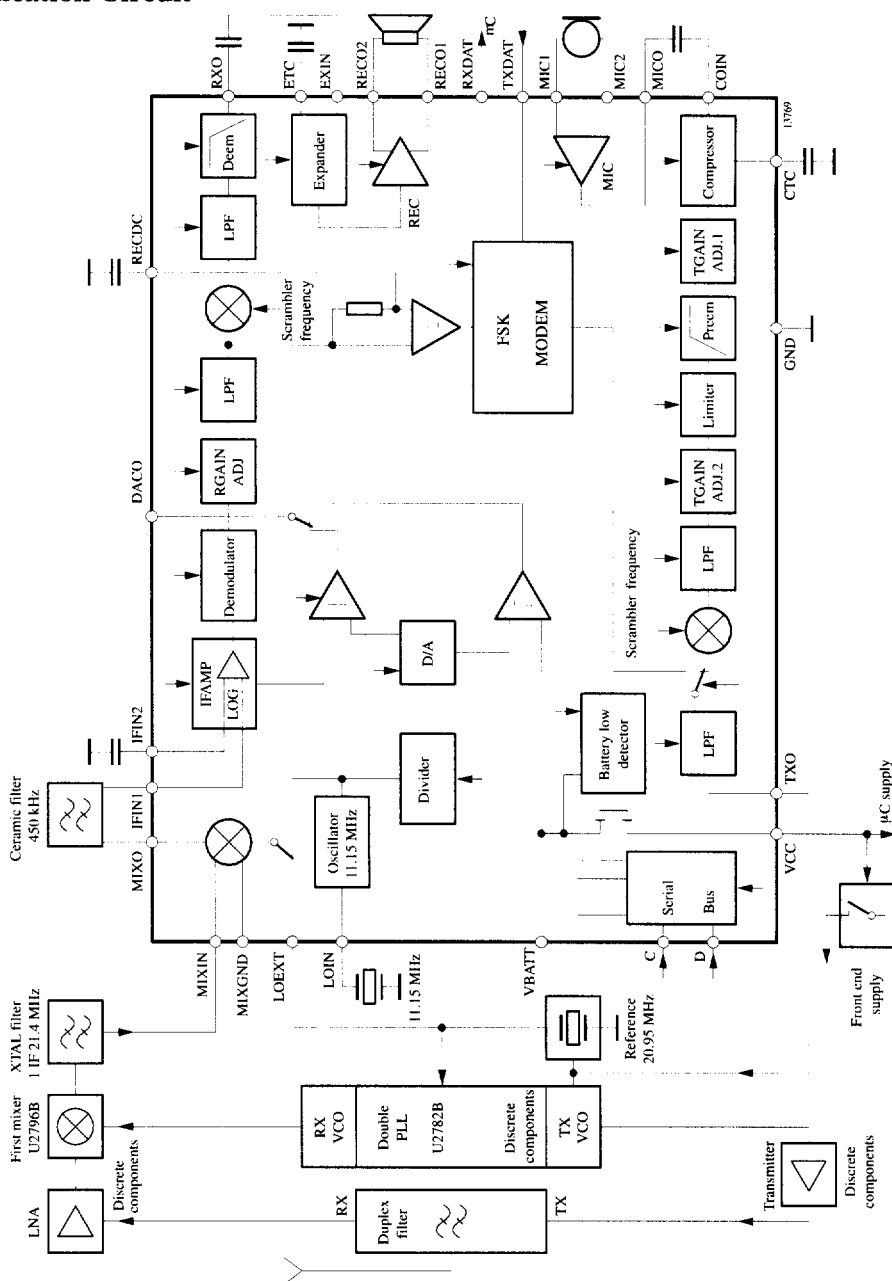


Figure 14. Application circuit

Package Information

Package SO28

Dimensions in mm

